16-Bit, 80 MSPS A/D Converter

AD10678

FEATURES

80 MSPS sample rate
80 dBFS signal-to-noise ratio
Transformer-coupled analog input
Single PECL clock source
Digital outputs
True binary format
3.3 V and 5 V CMOS compatible

APPLICATIONS

Low signature radar
Medical imaging
Communications instrumentation
Instrumentation
Antenna array processing

FUNCTIONAL BLOCK DIAGRAM

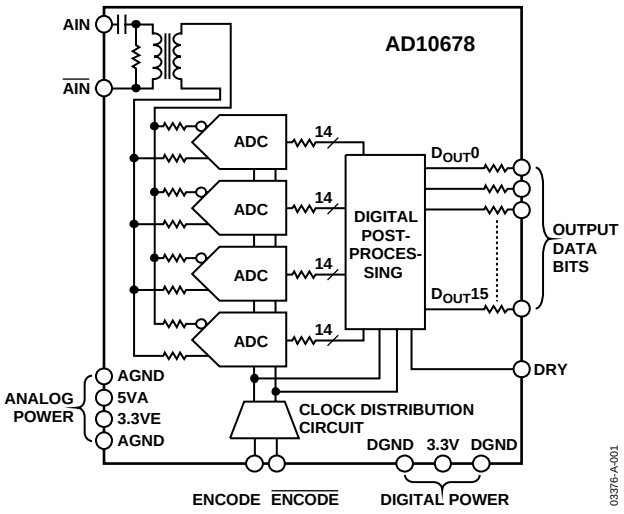


Figure 1.

GENERAL DESCRIPTION

The AD10678 is a 16-bit, high performance, analog-to-digital converter for applications that demand increased SNR levels. Exceptional noise performance and a typical signal-to-noise ratio of 80 dBFS are obtained by digitally postprocessing the outputs of four ADCs. Only a single analog input and PECL sampling clock, as well as 3.3 V and 5 V power supplies, are required.

The AD10678 is assembled using a 0.062" thick laminate board with three sets of connector interface pads to accommodate analog and digital isolation. Analog Devices recommends using this connector from Samtec: FSI-110-03-G-D-AD-K-TR. The overall card fits a 2.2" × 2.8" PCB specified from 0°C to 70°C.

PRODUCT HIGHLIGHTS

1. Guaranteed sample rate of 80 MSPS.
2. Input signal conditioning with optimized noise performance.
3. Fully tested and guaranteed performance.

Rev. A
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TABLE OF CONTENTS

Features 1
Applications 1
Functional block diagram 1
General Description 1
Product Highlights 1
Revision History 2
AD10678–Specifications 3
DC Specifications 3
Digital Specifications 3
AC Specifications 4
Switching Specifications 5
Explanation of Test Levels 5
Absolute Maximum Ratings 6
Operating Range 6
ESD Caution 6
Test Circuits 7
AD10678–Typical Performance Characteristics 10
Definition of Specifications 12
Thermal Considerations 12
Theory of Operation 13
Outline Dimensions 20
Ordering Guide 20

REVISION HISTORY

12/03—Data sheet changed from REV. 0 to REV.A

Updated format ..... Universal
Changes to AC Specifications table footnotes 4
Changes to Table 1 3
Changes to Table 3 6
Changes to Figure 11 10
Changes to Theory of Operation 13
Changes to Ordering Guide 20

AD10678–SPECIFICATIONS

DC SPECIFICATIONS

Table 1. AV_{CC} = 5 V, EV_{CC} = 3.3 V, V_{DD} = 3.3 V; T_A = 25°C, Differential Encode = 80 MSPS, C_{LOAD} ≤ 10 pF, unless otherwise noted.

Parameter	Test Level	Min	Typ	Max	Unit
RESOLUTION			16		Bits
Offset Error	I	–0.30	+0.12	+0.30	%FS
Gain Error	I	–7		+7	%FS
Differential Nonlinearity (DNL)	V		±0.7		LSB
Integral Nonlinearity (INL)	V		±4		LSB
TEMPERATURE DRIFT					
Offset Error	V		13		ppm/°C
Gain Error	V		200		ppm/°C
POWER SUPPLY REJECTION RATIO (PSRR)	V		60		dB
ANALOG INPUTS (AIN, $\overline{AIN}$)[1]					
Differential Input Voltage Range	V		2.15		V p-p
Differential Input Resistance	V		50		Ω
Differential Input Capacitance	V		2.5		nF
Input Bandwidth	IV	0.40		220	MHz
VSWR [2]	V		1.04:1		Ratio
POWER SUPPLY [3]					
Supply Current					
IAV_{CC} (AV_{CC} = 5.0 V)	I		0.95	1.1	A
IEV_{CC} (EV_{CC} = 3.3 V)	I		0.15	0.2	A
IV_{DD} (V_{DD} = 3.3 V)	I		0.49	0.625	A
Total Power Dissipation [4]	I		6.86	8.0	W

[1] Measurement includes the recommended interface connector.
[2] Input VSWR, see Figure 15.
[3] Supply voltages should remain stable within ±5% for normal operation.
[4] Power dissipation measures with encode at rated speed and –1 dBFS analog input at 10 MHz.

DIGITAL SPECIFICATIONS

Table 2. AV_{CC} = 5 V, EV_{CC} = 3.3 V, V_{DD} = 3.3 V; T_A = 25°C, Differential Encode = 80 MSPS, C_{LOAD} ≤ 10 pF, unless otherwise noted.

Parameter	Test Level	Min	Typ	Max	Unit
ENCODE INPUTS (ENCODE, $\overline{ENCODE}$)					
Differential Input Voltage Range	IV	0.4			V p-p
Differential Input Resistance	V		100		Ω
Differential Input Capacitance	V		160		pF
LOGIC OUTPUTS (D15 to D0)					
Logic Compatibility			CMOS		
Logic 1 Voltage—I_{LOAD} ≤100 mA	IV		0.9 × V_{DD}		V
Logic 0 Voltage—I_{LOAD} ≤100 mA	IV		0.4		V
Output Coding			True Binary		
Series Output Resistance—per Bit			120		Ω

AC SPECIFICATIONS

Table 3. AV_{CC} = 5 V, EV_{CC} = 3.3 V, V_{DD} = 3.3 V; TA = 25°C, Differential Encode = 80 MSPS, C_{LOAD} ≤ 10 pF, unless otherwise noted.

Parameter		Test Level	Min	Typ	Max	Unit
SNR [1]						
Analog Input	2.5 MHz	I	77.5	80.5		dBFS
@ –6 dBFS	10 MHz	I	77.5	80.5		dBFS
	30 MHz	I	77	80.2		dBFS
	70 MHz	I	76	78		dBFS
SINAD [2]						
Analog Input	2.5 MHz	I	77.2	80.3		dBFS
@ –6 dBFS	10 MHz	I	77.2	80.3		dBFS
	30 MHz	I	76.6	79.7		dBFS
	70 MHz	I	74.7	77.4		dBFS
SFDR [3]						
Analog Input	2.5 MHz	I	88	97.2		dBFS
@ –6 dBFS	10 MHz	I	88	97.2		dBFS
	30 MHz	I	84	94.2		dBFS
	70 MHz	I	81	91.7		dBFS
TWO-TONE [4]						
Analog Input						
@ –7 dBFS—IMD						
f1 = 10 MHz, f2 = 12 MHz		V		96		dBFS
f1 = 70 MHz, f2 = 72 MHz		V		84		dBFS

[1] Analog input signal power at –6 dBFS; signal-to-noise (SNR) is the ratio of signal level to total noise (first five harmonics removed). Encode = 80 MSPS. SNR is reported in dBFS, related back to converter full scale.
[2] Analog input signal power at –6 dBFS; signal-to-noise and distortion (SINAD) is the ratio of signal level to total noise + harmonics. Encode = 80 MSPS. SINAD is reported in dBFS, related back to converter full scale.
[3] Analog input signal equals –6 dBFS; SFDR is the ratio of converter full scale to worst spur.
[4] Both input tones at–7 dBFS; two tone intermodulation distortion (IMD) rejection is the ratio of either tone to the worst third-order intermodulation product.

SWITCHING SPECIFICATIONS

Table 4. AV_{CC} = 5 V, EV_{CC} = 3.3 V, V_{DD} = 3.3 V; T_A = 25°C, Differential Encode = 80 MSPS, C_{LOAD} ≤ 10 pF, unless otherwise noted.

Parameter	Test Level	Min	Typ	Max	Unit
MAXIMUM CONVERSION RATE	I	80			MSPS
MINIMUM CONVERSION RATE	IV			30	MSPS
DUTY CYCLE	IV	40		60	%
ENCODE INPUTS PARAMETERS					
Encode Period @ 80 MSPS, t_{ENC}	V		12.5		ns
Encode Pulse Width High @ 80 MSPS, t_{ENCH}	V		6.25		ns
Encode Pulse Width Low @ 80 MSPS, t_{ENCL}	V		6.25		ns
ENCODE/DATA (D15:D0)					
Propagation Delay, t_{PDH}			6.7		ns
Valid Time, t_{PDL}			7.3		ns
ENCODE/DATA READY[1]					
Encode Rising to Data Ready Falling, t_{DR_F}			12.6		ns
Encode Rising to Data Ready Rising, t_{DR_R}			6.4		ns
DATA READY/DATA[1]					
Data Ready to Data (Hold Time)—t_{H_DR}			10		ns
Data Ready to Data (Setup Time)—t_{S_DR}			1		ns
APERTURE DELAY, t_A	V		480		ps
APERTURE UNCERTAINTY (JITTER), t_J	V		500		fs rms
PIPELINE DELAYS	V		10		Cycles

[1] Duty Cycle = 50%.

EXPLANATION OF TEST LEVELS

I. 100% production tested.
II. 100% production tested at 25°C and sample tested at specified temperatures.
III. Sample tested only.
IV. Parameter is guaranteed by design and characterization testing.
V. Parameter is a typical value only.
VI. 100% production tested at 25°C; guaranteed by design and characterization testing for industrial temperature range; 100% production tested at temperature extremes for military devices.

ABSOLUTE MAXIMUM RATINGS

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 5. AD10678 Stress Ratings

Parameter	Rating
AV_{CC} to AGND	0 V to 7 V
EV_{CC} to AGND	0 V to 6 V
V_{DD} to DGND	–0.5 V to +3.8 V
Analog Input Voltage	0 V to AV_{CC}
Analog Input Current	25 mA
Encode Input Voltage	0 V to 5 V
Digital Output Voltage	–0.5 V to V_{DD}
Maximum Junction Temperature	150°C
Storage Temperature Range Ambient	–65°C to +150°C
Maximum Operating Temperature Ambient	92°C

OPERATING RANGE

Operating Ambient Temperature Range: 0°C to 70°C. See Thermal Considerations section.

Table 6. Output Coding (True Binary)

Code	AIN (V)	Digital Output
65535	+1.1	1111 1111 1111 1111
.	.	.
.	.	.
.	.	.
32768	0	1000 0000 0000 0000
32767	–0.000034	0111 1111 1111 1111
.	.	.
.	.	.
.	.	.
0	–1.1	0000 0000 0000 0000

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



TEST CIRCUITS

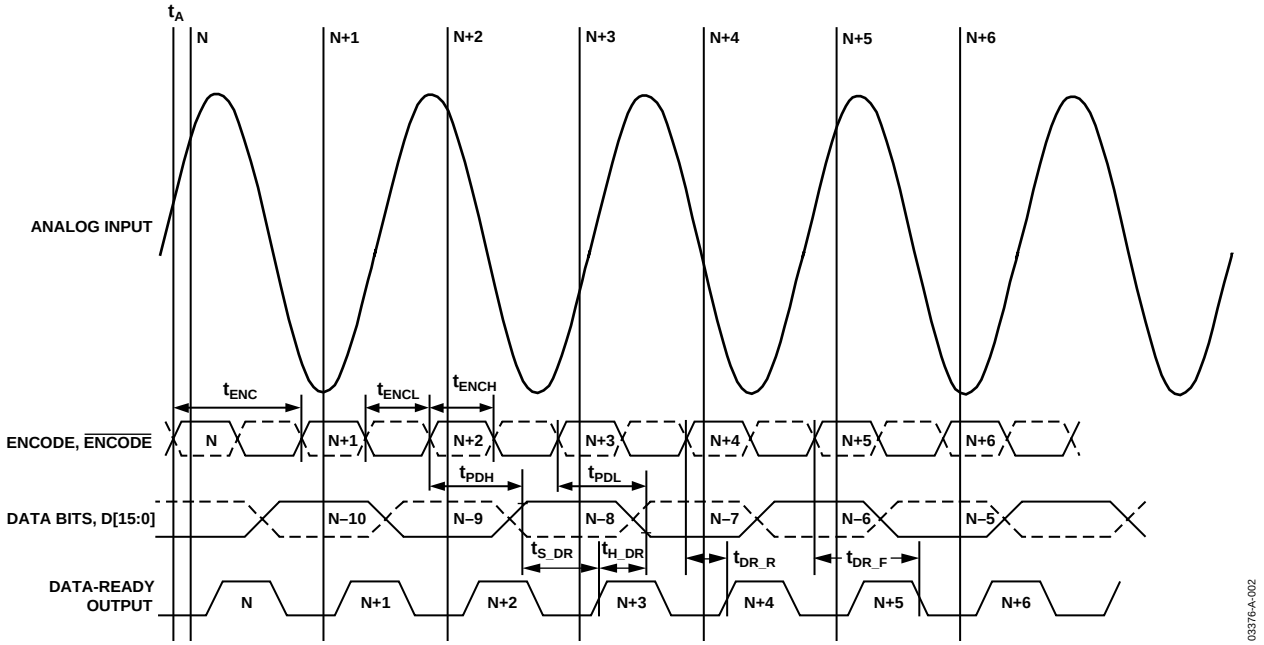


Figure 2. Timing Diagram

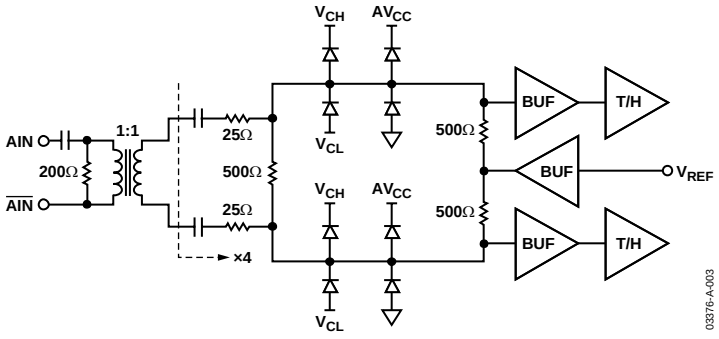


Figure 3. Analog Input Stage

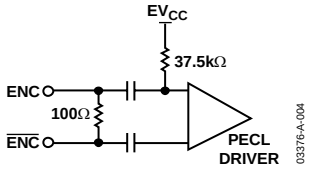


Figure 4. Equivalent Encode Input

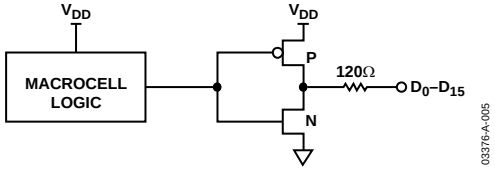


Figure 5. Digital Output Stage

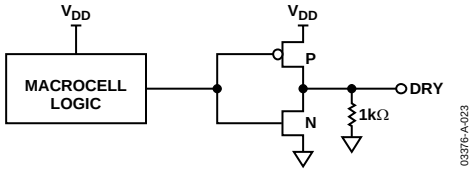


Figure 6. Data-Ready Output

Table 7. Interfaces 1 and 2: Digital Pin Function Descriptions

P1: Pin Number	Mnemonic	Function	P2: Pin Number	Mnemonic	Function
1	DGND	Digital Ground	1	DGND	Digital Ground
2	DGND	Digital Ground	2	DGND	Digital Ground
3	$D_{OUT}15$	Data Bit Output	3	+3.3VD	Digital Voltage (V_{DD})
4	NC	No Connection	4	$D_{OUT}0$	Data Bit Output
5	$D_{OUT}14$	Data Bit Output	5	+3.3VD	Digital Voltage (V_{DD})
6	DGND	Digital Ground	6	$D_{OUT}1$	Data Bit Output
7	$D_{OUT}13$	Data Bit Output	7	+3.3VD	Digital Voltage (V_{DD})
8	NC	No Connection	8	$D_{OUT}2$	Data Bit Output
9	$D_{OUT}12$	Data Bit Output	9	DGND	Digital Ground
10	DGND	Digital Ground	10	$D_{OUT}3$	Data Bit Output
11	$D_{OUT}11$	Data Bit Output	11	DGND	Digital Ground
12	NC	No Connection	12	$D_{OUT}4$	Data Bit Output
13	$D_{OUT}10$	Data Bit Output	13	DGND	Digital Ground
14	DGND	Digital Ground	14	$D_{OUT}5$	Data Bit Output
15	$D_{OUT}9$	Data Bit Output	15	DGND	Digital Ground
16	NC	No Connection	16	$D_{OUT}6$	Data Bit Output
17	$D_{OUT}8$	Data Bit Output	17	+3.3VD	Digital Voltage (V_{DD})
18	DGND	Digital Ground	18	$D_{OUT}7$	Data Bit Output
19	DGND	Digital Ground	19	+3.3VD	Digital Voltage (V_{DD})
20	DRY	Data Ready Output	20	DGND	Digital Ground

Table 8 Interface 3: Analog Pin Function Descriptions

P3: Pin Number	Mnemonic	Function
1	+3.3VE	Encode Voltage (EV_{CC})
2	+5.0VA	Analog Voltage (AV_{CC})
3	+3.3VE	Encode Voltage (EV_{CC})
4	+5.0VA	Analog Voltage (AV_{CC})
5	AGND	Analog Ground
6	+5.0VA	Analog Voltage (AV_{CC})
7	AGND	Analog Ground
8	+5.0VA	Analog Voltage (AV_{CC})
9	AGND	Analog Ground
10	AGND	Analog Ground
11	AGND	Analog Ground
12	AIN	Analog Input
13	AGND	Analog Ground
14	$\overline{\text{AIN}}$	$\overline{\text{Analog Input}}$
15	ENCODE	Encode Input
16	AGND	Analog Ground
17	$\overline{\text{ENCODE}}$	$\overline{\text{Encode Input}}$
18	AGND	Analog Ground
19	AGND	Analog Ground
20	AGND	Analog Ground

Top View of Interface PCB Assembly
Dimensions shown in inches
Tolerances:
0.xx = ±10 mils
0.xxx = ±5 mils

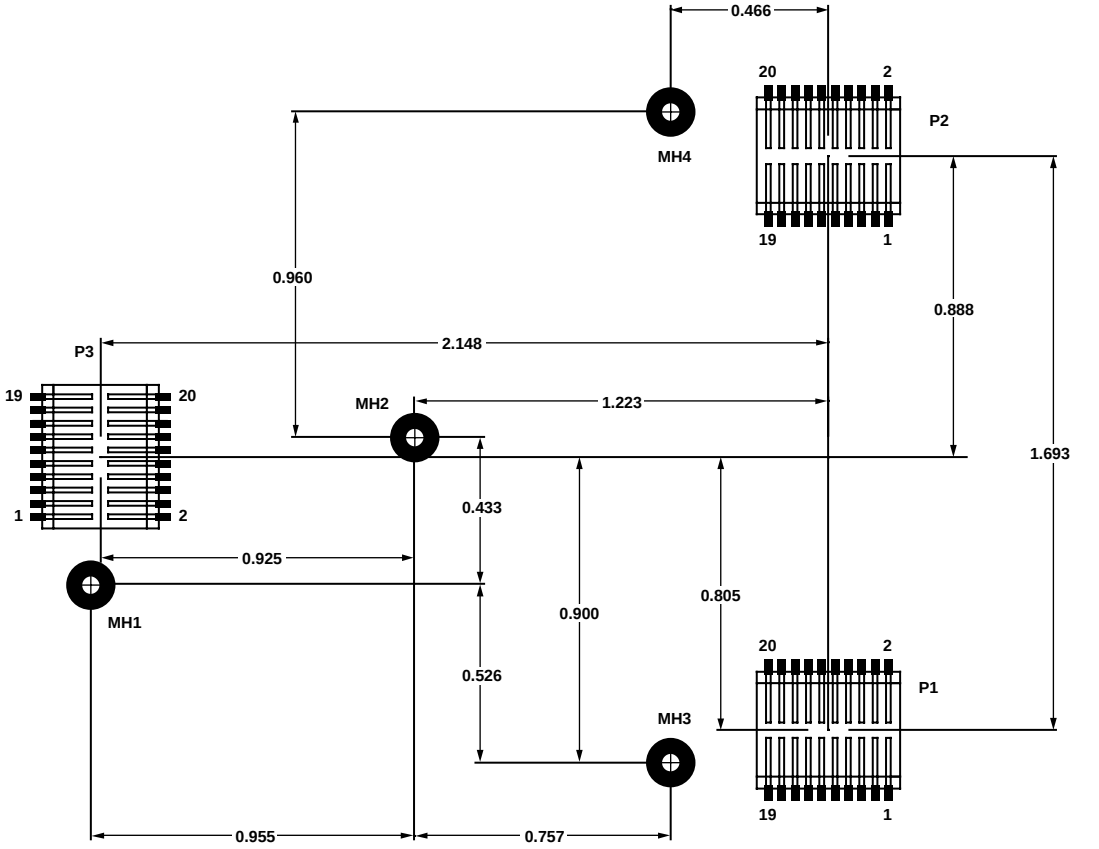


Figure 7. Header Interface Dimensions (Inches)

AD10678–TYPICAL PERFORMANCE CHARACTERISTICS

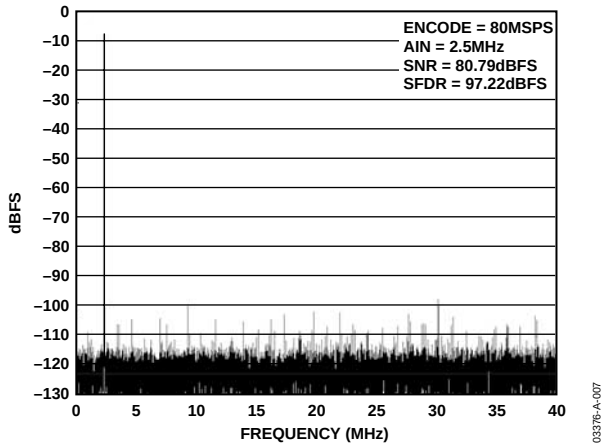


Figure. 8. Single-Tone at 2.5 MHz

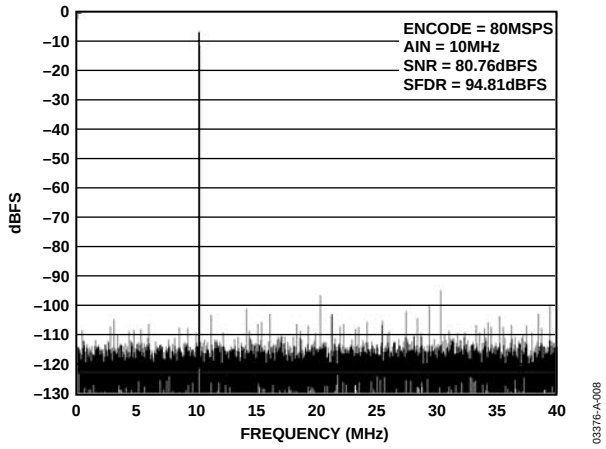


Figure 9. Single-Tone at 10 MHz

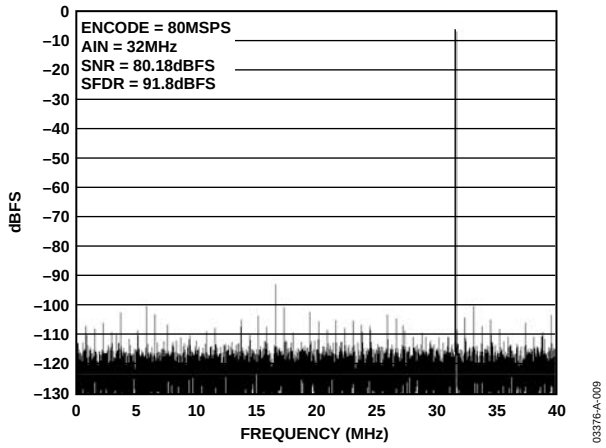


Figure 10. Single-Tone at 32 MHz

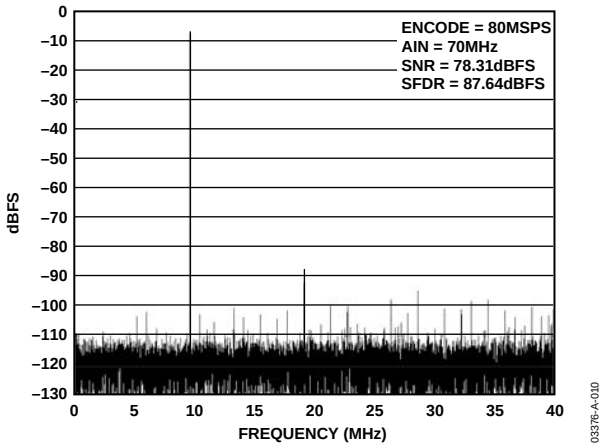


Figure 11. Single-Tone at 70 MHz

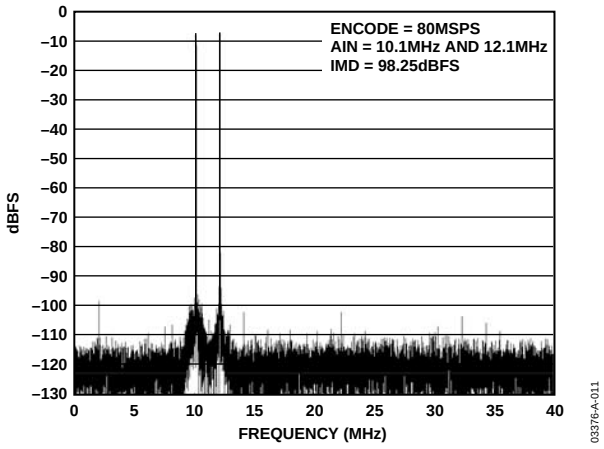


Figure 12. Two-Tone at 10.1 MHz and 12.1 MHz

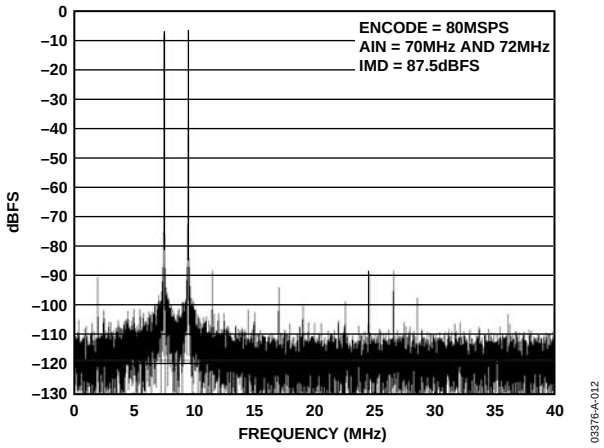


Figure 13. Two-Tone at 70 MHz and 72 MHz

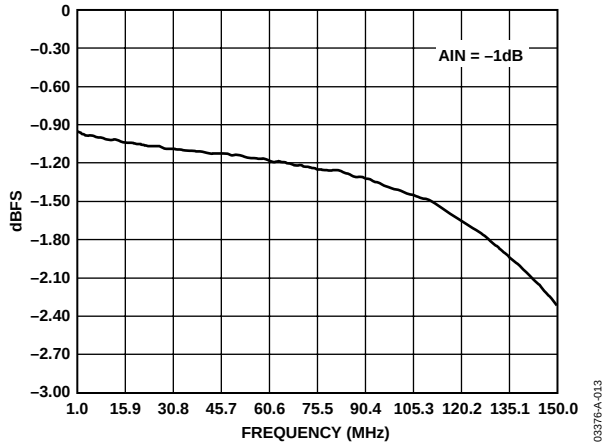


Figure 14. Gain Flatness

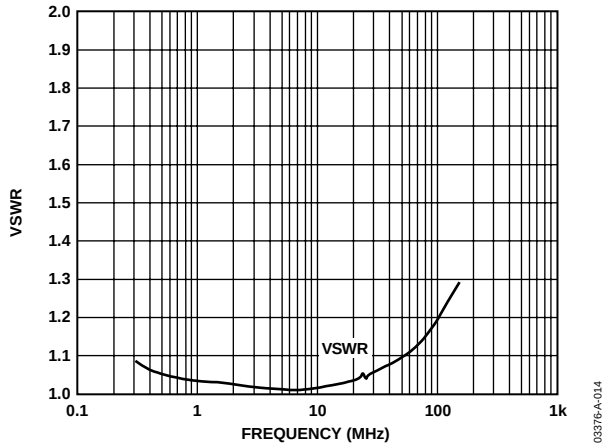


Figure 15. Analog Input VSWR

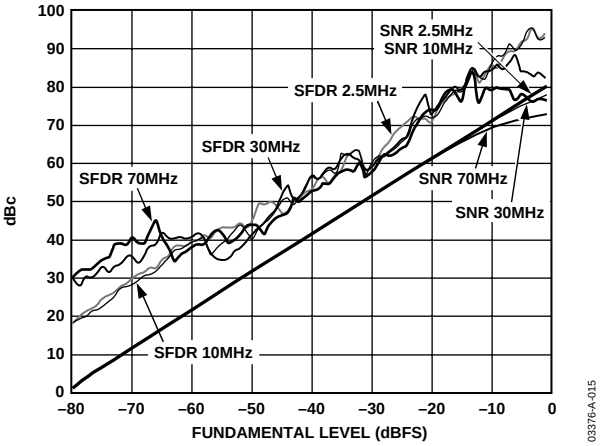


Figure 16. SFDR and SNR vs. Analog Input Level

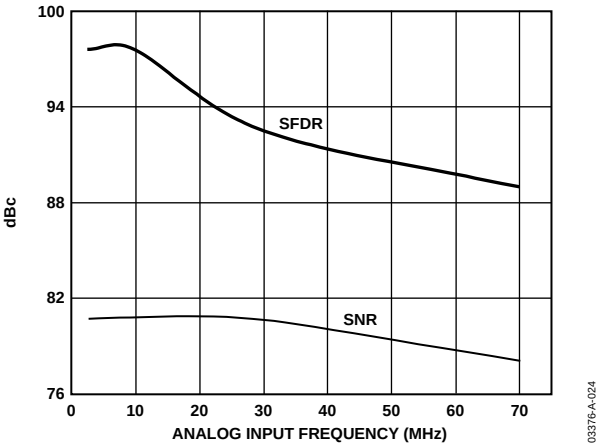


Figure 17. SFDR and SNR vs. Analog Input Frequency

DEFINITION OF SPECIFICATIONS

Analog Bandwidth
The analog input frequency at which the spectral power of the fundamental frequency (as determined by the FFT analysis) is reduced by 3 dB.

Aperture Delay
The delay between the 50% point on the rising edge of the ENCODE command and the instant at which the analog input is sampled.

Aperture Uncertainty (Jitter)
The sample-to-sample variation in aperture delay.

Differential Nonlinearity
The deviation of any code from an ideal 1 LSB step.

Integral Nonlinearity
The deviation of the transfer function from a reference line measured in fractions of 1 LSB using a "best straight line" determined by a least square curve fit.

Encode Pulse Width/Duty Cycle
Pulse width high is the minimum amount of time that the ENCODE pulse should be left in Logic 1 state to achieve rated performance; pulse width low is the minimum time that the ENCODE pulse should be left in low state. At a given clock rate, these specifications define an acceptable encode duty cycle.

Harmonic Distortion
The ratio of the rms signal amplitude to the rms value of the worst harmonic component.

Minimum Conversion Rate
The encode rate at which the SNR of the lowest analog signal frequency drops by no more than 3 dB below the guaranteed limit.

Maximum Conversion Rate
The encode rate at which parametric testing is performed.

Output Propagation Delay
The delay between the 50% point of the rising edge of the ENCODE command and the time when all output data bits are within valid logic levels.

Power Supply Rejection Ratio
The ratio of a change in output offset voltage to a change in power supply voltage.

Signal-to-Noise-and-Distortion (SINAD)
The ratio of the rms signal amplitude (set at 1 dB below full scale) to the rms value of the sum of all other spectral components, including the first five harmonics and dc. May be reported in dBc (i.e., degrades as signal level is lowered) or in dBFS (always related back to converter full scale).

Signal-to-Noise Ratio (SNR)
The ratio of the rms signal amplitude (set at 1 dB below full scale) to the rms value of the sum of all other spectral components, excluding the first five harmonics and dc. May be reported in dBc (i.e., degrades as signal level is lowered) or in dBFS (always related back to converter full scale).

Spurious-Free Dynamic Range (SFDR)
The ratio of the rms signal amplitude to the rms value of the peak spurious spectral component. The peak spurious component may or may not be a harmonic. May be reported in dBc (i.e., degrades as signal level is lowered) or in dBFS (always related back to converter full scale).

Two-Tone Intermodulation Distortion Rejection (IMD)
Ratio of the rms value of either input tone to the rms value of the worst third-order intermodulation product; reported in dBc.

Voltage Standing-Wave Ratio (VSWR)
The ratio of the amplitude of the elective field at a voltage maximum to that at an adjacent voltage minimum.

THERMAL CONSIDERATIONS

Due to the high power nature of the part, it is critical that the following thermal conditions be met for the part to perform to data sheet specifications. This also ensures that the maximum junction temperature (150°C) is not exceeded.

- Operation temperature (t_A) must be within 0°C to 70°C.
- All mounting standoffs should be fastened to the interface PCB assembly with 2-56 nuts. This ensures good thermal paths as well as excellent ground points.
- The unit rises to ~72°C (t_C) on the heat sink in still air (0 linear feet per minute (LFM)). The minimum recommended air flow is 100 linear feet per minute (LFM) in either direction across the heat sink (see Figure 18).

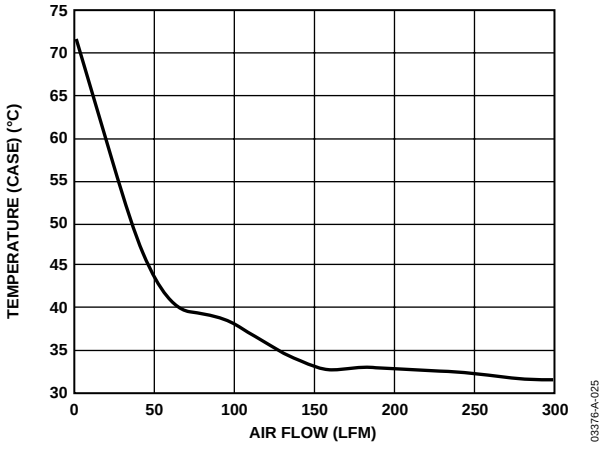


Figure 18. Temperature (Case) vs. Air Flow (Ambient)

THEORY OF OPERATION

The AD10678 employs four parallel, high speed analog-to-digital converters in a correlation technique to improve the dynamic range of the ADCs. The technique consists of summing the parallel outputs of the four converters to reduce the uncorrelated noise introduced by the individual converters. Signals processed through the high speed adder are correlated and summed coherently. Noise is not correlated and sums on an rms basis.

The four high speed, analog-to-digital converters employ a three-stage subrange architecture. The AD10678 provides complementary analog input pins, AIN and $\overline{\text{AIN}}$. Each analog input is centered around 2.4 V and should swing ±0.55 V around the reference. Since AIN and $\overline{\text{AIN}}$ are 180 degrees out of phase, the differential analog input signal is 2.15 V p-p.

The analog input is designed for a 50 Ω input impedance for easy interface to commercially available cables, filters, and drivers, etc.

The AD10678 encode inputs are ac-coupled to a PECL differential receiver/driver. The output of the receiver/driver provides a clock source for a 1:5 PECL clock driver and a PECL-to-TTL translator. The 1:5 PECL clock driver provides the differential encode signal for each of the four high speed analog-to-digital converters. The PECL-to-TTL translator is used to provide a clock source for the complex programmable logic device (CPLD).

The digital outputs from the four ADCs drive 120 Ω series output terminators and are applied to the CPLD for postprocessing. The digital outputs are added together in the complex programmable logic device through a ripple-carry adder, which provides the 16-bit data output. The AD10678 provides valid data following 10 pipeline delays. The result is a 16-bit parallel digital CMOS compatible word coded as true binary.

Input Stage

The user is provided with a single-to-differential transformer coupled input. The input impedance is 50 Ω and requires a 2.15 V p-p input level to achieve full scale.

Encoding the AD10678

The AD10678 encode signal must be a high quality, low phase noise source to prevent performance degradation. The clock input must be treated as an analog input signal because aperture jitter may affect dynamic performance. For optimum performance, the AD10678 must be clocked differentially.

Output Loading

Take care when designing the data receivers for the AD10678. The complex programmable logic device 16-bit outputs drive 120 Ω series resistors to limit the amount of current that can flow into the output stage. To minimize capacitive loading, there should only be one gate on each of the output pins. A typical CMOS gate combined with the PCB trace has a load of approximately 10 pF. It should be noted that extra capacitive loading increases output timing and invalidates timing specifications. Digital output timing is guaranteed with a 10 pF load.

Analog and Digital Power Supplies

Care must be taken when selecting a power source. Linear supplies are recommended. Switching supplies tend to have radiated components that may be coupled into the ADCs. The AD10678 features separate analog and digital supply and ground currents, helping to minimize digital corruption of sensitive analog signals.

The +3.3VE supply provides power to the clock distribution circuit. The +3.3VD supply provides power to the digital output section of the ADCs, the PECL-to-TTL translator, and the CPLD. Separate +3.3VE and +3.3VD supplies are used to prevent modulation of the clock signal with digital noise. The +5VA supply provides power to the analog sections of the ADCs. Decoupling capacitors are strategically placed throughout the circuit to provide low impedance noise shunts to ground. The +5VA supply (analog power) should be decoupled to AGND (analog ground) and +3.3VD (digital power) should be decoupled to DGND (digital ground). The +3.3VE supply (analog power) should be decoupled to AGND. The evaluation board schematic and layout data provide a typical PCB implementation of the AD10678.

Analog and Digital Grounding

Although the AD10678 provides separate analog and digital ground pins, the device should be treated as an analog component. Proper grounding is essential in high speed, high resolution systems. Multilayer printed circuit boards are recommended to provide optimal grounding and power distribution. The use of power and ground planes provides distinct advantages. Power and ground planes minimize the loop area encompassed by a signal and its return path, minimize the impedance associated with power and ground paths, and provide a distributed capacitor formed by the power plane, printed circuit board material, and ground plane. The AD10678 unit is provided with four metal standoffs (see Figure 7). MH2 is located in the center of the unit and MH1 is located directly below analog header P3. Both of these standoffs are tied to analog ground and should be connected accordingly on the next level assembly for optimum performance. The two standoffs located near P1 and P2 (MH3 and MH4) are tied to digital ground and should be connected accordingly on the next-level assembly.

Other Notes

The circuit is configured on a 2.2" × 2.8" laminate board with three sets of connector interface pads. The pads are configured in such a way that easy "keying" is provided to the user. The pads are made for low profile applications and have a total height of 0.12" after mating. The part numbers for the header mates are provided in Figure 7. All pins of the analog and digital sections are described in Table 7 and Table 8.

Evaluation Board

The AD10678 evaluation board provides an easy way to test the 16-bit 80 MSPS A/D converter. The board requires a clock source, an analog input signal, two 3.3 V power supplies, and a 5 V power supply. The clock source is buffered on the board to provide the clock for the AD10678, a latch, and a data ready signal. To use the AD10678 data ready output to clock the buffer memory, remove R24 (0.0 Ω) and install a 0.0 Ω resistor at R31 (DNI). The ADC digital outputs are latched on board by a 74LCX16374. The digital outputs and output clock are available on a 40-pin connector J1. Power is supplied to the board via uninsulated metal banana jacks.

The analog input is connected via an SMA connector AIN. The analog input section provides for a single-ended input option or a differential input option. The board is shipped in a single-ended analog input option. Removing a ground tie at E17 converts the circuit to a differential analog input configuration.

Table 9. PCB Bill of Material

Item	Quantity	Reference Designator	Description
1	1	J1	Connector, 40-Position Header, Male Straight
2	1	U1	IC, LV 16-Bit D-Type Flip-Flop with 5 V Tolerant I/O
3	3	L1 to L3	Common-Mode Surface-Mount Ferrite Bead 20 Ω
4	3	J11 to J13	Connector, 1 mm Single Element Interface
5	6	P1, P2, P8 to P10, P12	Uninsulated BANANA JACK All Metal
6	2	U5, U6	IC, 3.3 V/5 V ECL Differential Receiver/Driver
7	1	U7	IC, 3.3 V Dual Differential LVPECL to LVTTL Translator
8	1	R24	RES 0.0 Ω 1/10 W 5% 0805 SMD
9	19	R0 to R16, R20, R23	RES 51.1 Ω 1/10 W 1% 0805 SMD
10	1	R17	RES 18.2 kΩ 1/10 W 1% 0805 SMD
11	4	R18, R19, R21, R22	RES 100 Ω 1/10 W 1% 0805 SMD
12	17	C1, C10 to C13, C16 to C18, C23 to C26, C29 to C32	CAP 0.1 µF 16 V CERAMIC X7R 0805
13	6	C8, C9, C4, C15, C27, C33	CAP 10 µF 10 V CERAMIC Y5V 1206
14	4	J2, J3, J5, J6	CONNECTOR, SMA JACK 200 Mil STR GOLD
15	1	A1	ASSEMBLY, AD10678BWS
16	1	AD106xx Evaluation Board	GS04483 (PCB)

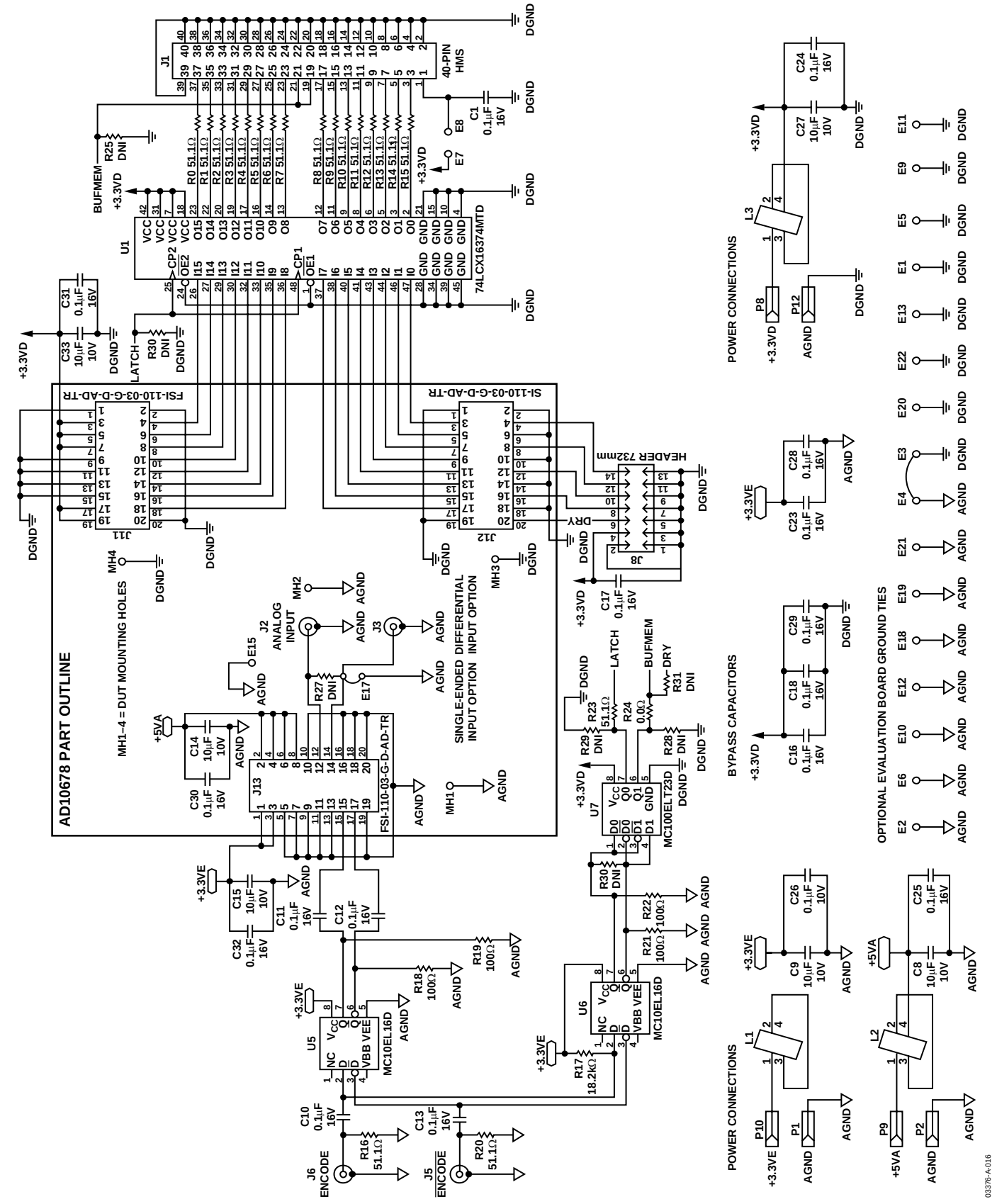


Figure 19. Evaluation Board Schematic

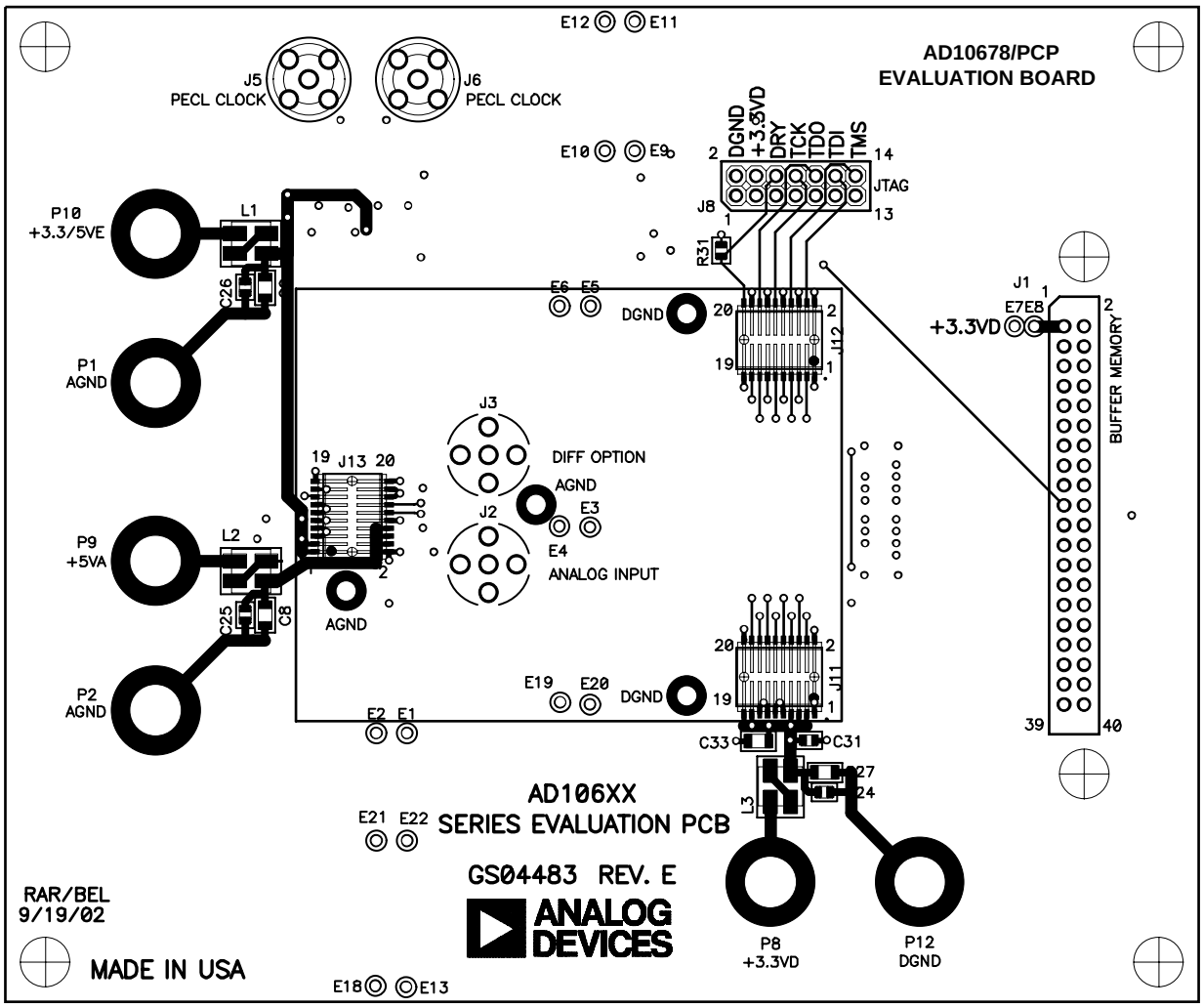


Figure 20. Evaluation Board Mechanical Layout Top View

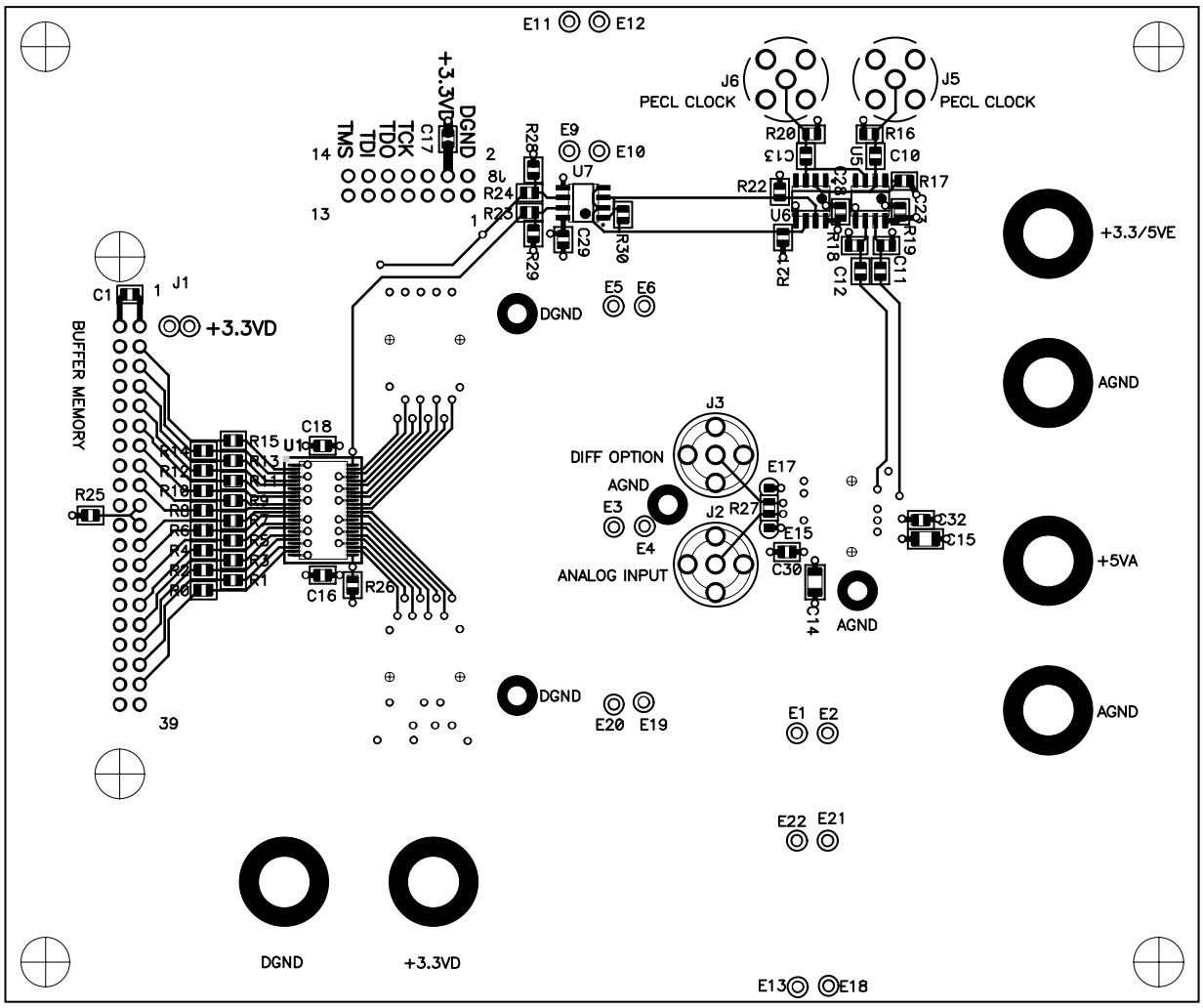


Figure 21. Evaluation Board Mechanical Layout Bottom View

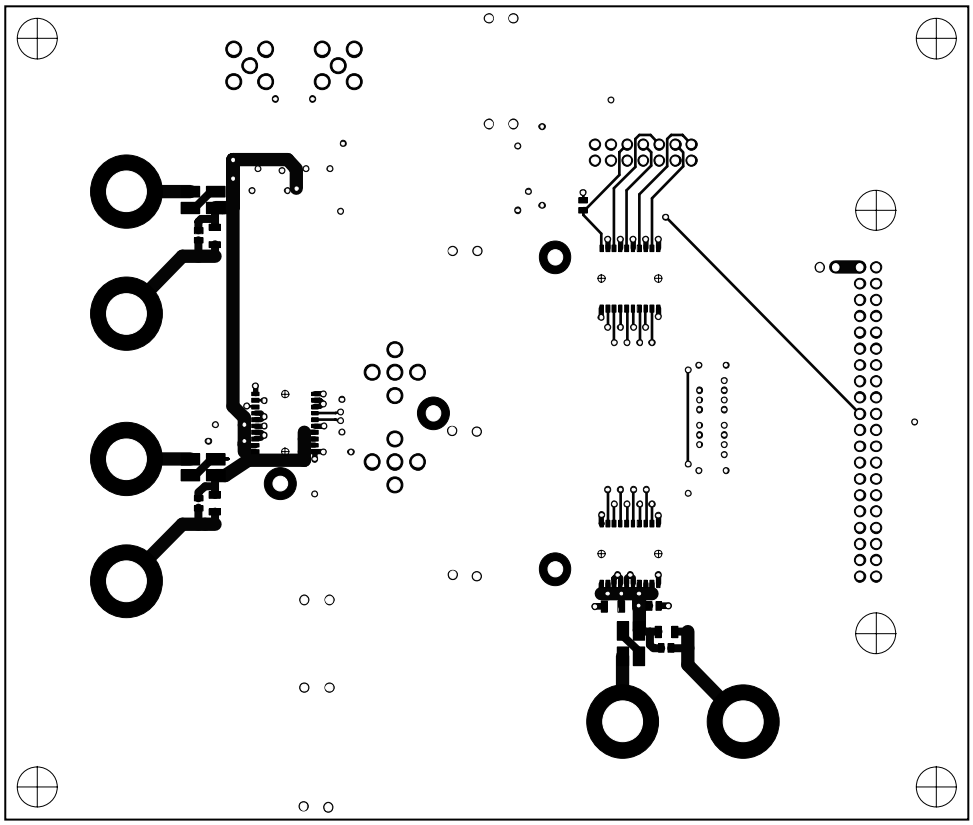


Figure 22. Evaluation Board Top Layer Copper

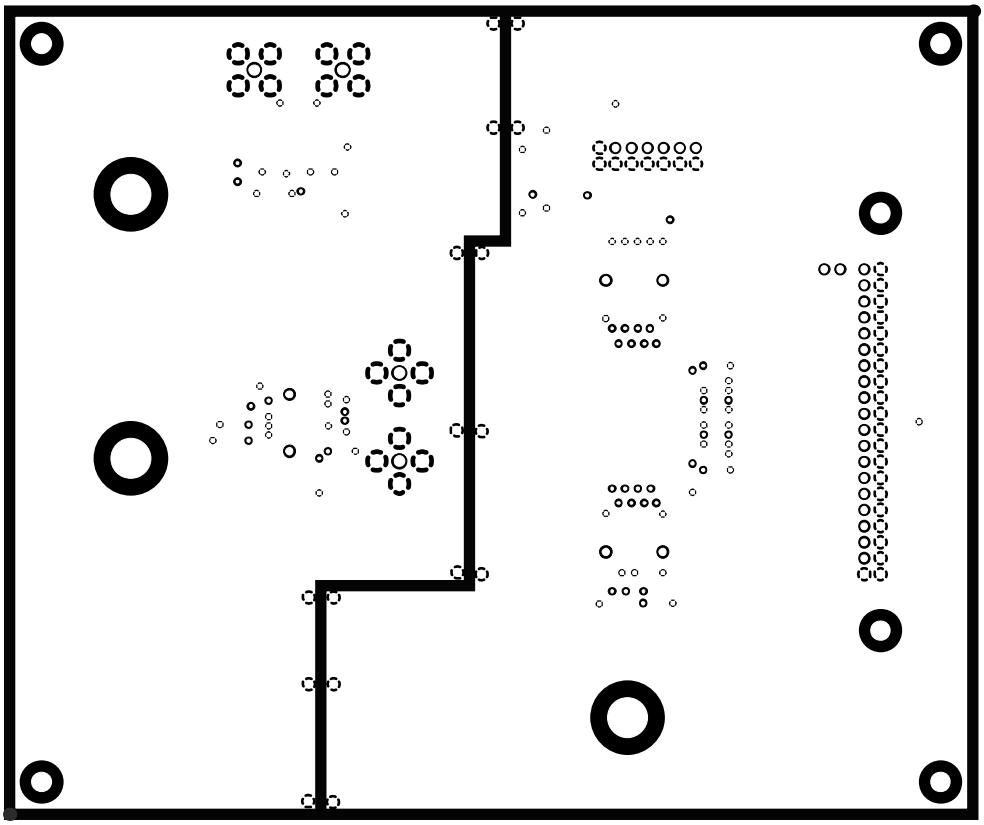


Figure 23. Evaluation Board Second Layer Copper

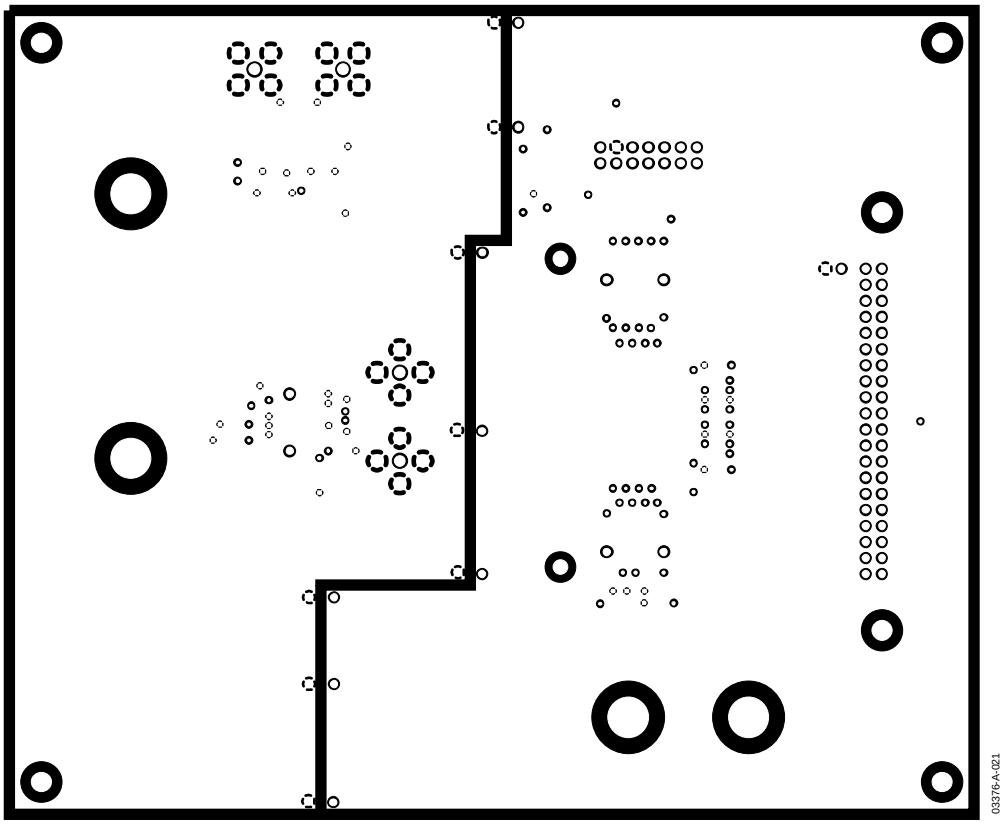


Figure 24. Evaluation Board Third Layer Copper

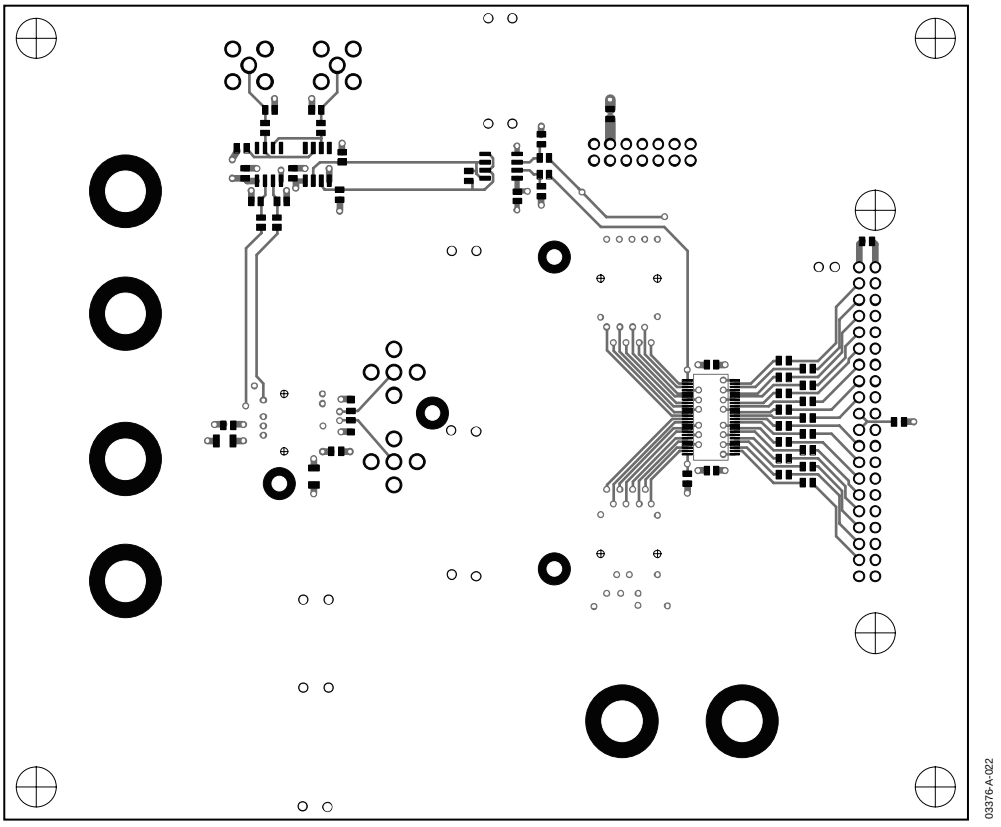


Figure 25. Evaluation Board Bottom Layer Copper

OUTLINE DIMENSIONS

Dimensions shown in inches
Tolerances:
0.xx = ±10 mils
0.xxx = ±5 mils

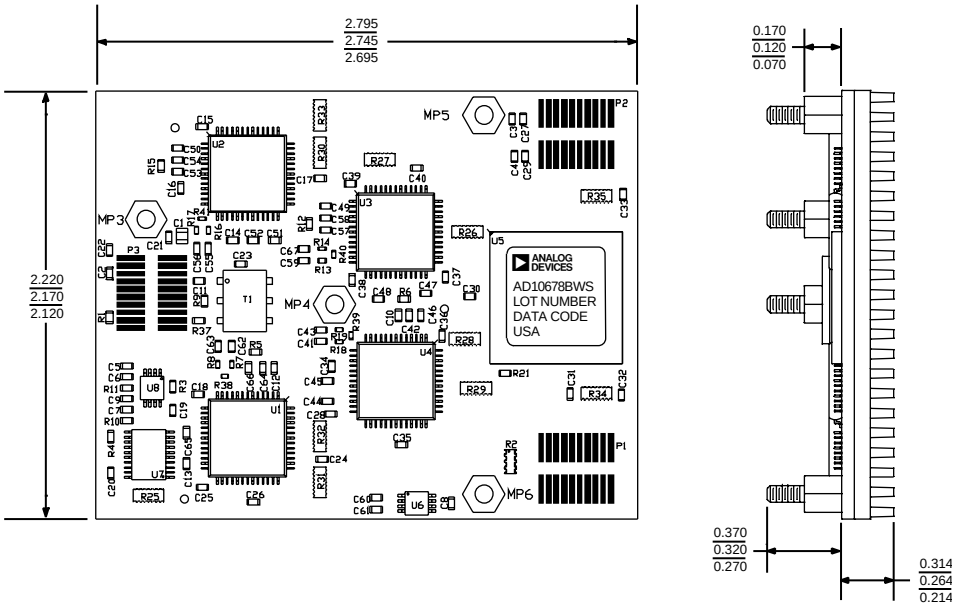


Figure 26.

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD10678BWS	0°C to 70°C	Non-Herm Hybrid Surf Mount (2.2" × 2.8")	WS-120
AD10678/PCB	25°C	Evaluation Board	

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